CMOS Digital Integrated Circuits Silicon Monolithic

74VHCV574FT

1. Functional Description

Octal Schmitt D-Type Flip-Flop with 3-State Outputs

2. General

The 74VHCV574FT is advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ($\overline{\text{OE}}$).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHCV574FT is capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

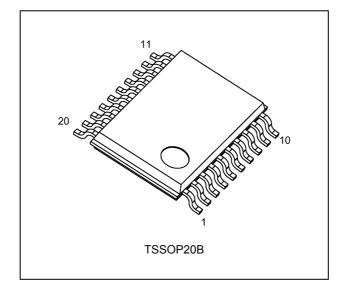
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state.

3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: f_{MAX} = 180 MHz (typ.) at V_{CC} = 5.0 V
- (4) Low power dissipation: $I_{CC} = 2.0 \ \mu A \ (max)$ at $T_a = 25^{\circ}C$
- (5) Wide operating voltage range: $V_{CC(opr)} = 1.8 \text{ V to } 5.5 \text{ V}$
- (6) Output current: $|I_{OH}|/I_{OL} = 16 \text{ mA (min)}(V_{CC} = 4.5 \text{ V})$
- (7) Power-down protection is provided on all inputs and outputs.
- (8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 574 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

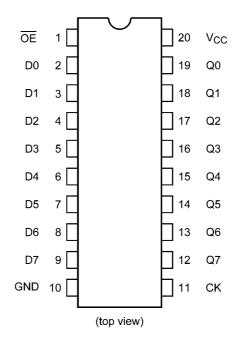
4. Packaging



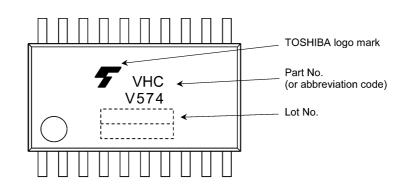
Start of commercial production 2014-07 2016-08-05 Rev.2.0

5. Pin Assignment

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6. Marking



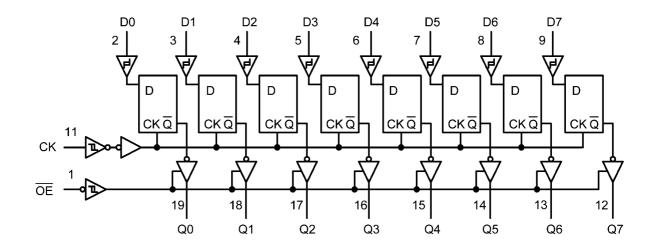
7. Truth Table

	Inputs	puts Outr		
ŌĒ	СК	D	Output	
н	Х	Х	Z	
L		Х	Qn	
L		L	L	
L		Н	Н	

- X: Don't care
- Z: High impedance
- Qn: No change

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8. System Diagram



9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-50	mA
Output diode current	Ι _{ΟΚ}	(Note 3)	±50	mA
Output current	I _{OUT}		±50	mA
Power dissipation	PD	(Note 4)	180	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

Note 4: 180 mW in the range of $T_a = -40$ to 85 °C. From $T_a = 85$ to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Note	Rating	Unit
Supply voltage	V _{CC}	—		1.8 to 5.5	V
Input voltage	V _{IN}	—		0 to 5.5	V
Output voltage	V _{OUT}	—	(Note 1)	0 to 5.5	V
			(Note 2)	0 to V _{CC}	
Operating temperature	T _{opr}	—		-40 to 125	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 \pm 0.3 V		0 to 20	ms/V
		V_{CC} = 5 \pm 0.5 V		0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.

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11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Conditio	on	V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V _P	_	1.8	_	_	1.65	V	
			2.3	_	_	1.85	1	
				3.0	_	_	2.20	
				4.5	_	_	3.15	1
				5.5	_	_	3.85	
Negative threshold voltage	V _N	—		1.8	0.15	_	_	V
				2.3	0.45	_	_	1
				3.0	0.90	_	_	
				4.5	1.35	_	_	
				5.5	1.65	_	_	1
Hysteresis voltage	V _H	_		1.8	0.15	_	1.05	V
				2.3	0.20	_	1.10	
				3.0	0.30	_	1.20	1
				4.5	0.40	_	1.40	
				5.5	0.50	_	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	1.8	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -8 mA	3.0	2.58	_	_	
			I _{OH} = -16 mA	4.5	3.94	—		
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 50 μA	1.8	_	0.0	0.1	
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 8 mA	3.0	_	_	0.36	
			I _{OL} = 16 mA	4.5	—	—	0.44	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.8 to 5.5	—	—	±0.5	μA
Power-OFF leakage current	I _{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0	_	_	0.5	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	_	±0.1	μA
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	—	—	2.0	μA

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Conditior	ı	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	VP	—		1.8	_	1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5	_	3.15	
				5.5	—	3.85	
Negative threshold voltage	V _N	—		1.8	0.15	—	V
				2.3	0.45	—	
				3.0	0.90	—	
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	—		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	1
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I _{OH} = -8 mA	3.0	2.48	—	
			I _{OH} = -16 mA	4.5	3.80	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 8 mA	3.0	_	0.44	
			I _{OL} = 16 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.8 to 5.5	—	±5.0	μΑ
Power-OFF leakage current	I _{OFF}	V_{IN}/V_{OUT} = 5.5 V		0	—	5.0	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	±1.0	μA
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	20.0	μA

11.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Conditior	ı	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	—	—			1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V _N	—		1.8	0.15	—	V
				2.3	0.45	—	
				3.0	0.90	—	
				4.5	1.35	_	
				5.5	1.65	—	
Hysteresis voltage	V _H	—		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	1.8	1.7	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I _{OH} = -8 mA	3.0	2.40	—	
			I _{OH} = -16 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 8 mA	3.0	_	0.55	
			I _{OL} = 16 mA	4.5	_	0.65	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.8 to 5.5	_	±20.0	μA
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0		20.0	μA
Input leakage current	l _{iN}	V _{IN} = 5.5 V or GND		0 to 5.5		±2.0	μΑ
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	40.0	μA

11.4. Timing Requirements (Unless otherwise specified, $T_a = 25^{\circ}C$, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	5.0	1
		5.0 ± 0.5	5.0]
Minimum setup time	ts	2.5 ± 0.2	5.5	ns
		3.3 ± 0.3	3.5	
		5.0 ± 0.5	3.5	
Minimum hold time	t _h	2.5 ± 0.2	2.0	ns
		3.3 ± 0.3	1.5]
		5.0 ± 0.5	1.5]

11.5. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 85°C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (CK)	t _{w(L)} ,t _{w(H)}	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	5.0	
		5.0 ± 0.5	5.0	
Minimum setup time	t _S	2.5 ± 0.2	5.5	ns
		3.3 ± 0.3	3.5	
		5.0 ± 0.5	3.5	
Minimum hold time	t _h	2.5 ± 0.2	2.0	ns
		3.3 ± 0.3	1.5	
		5.0 ± 0.5	1.5	

11.6. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	5.0	
		5.0 ± 0.5	5.0	
Minimum setup time	t _s	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	4.5	
		5.0 ± 0.5	4.0	
Minimum hold time	t _h	2.5 ± 0.2	2.0	ns
		3.3 ± 0.3	1.5	
		5.0 ± 0.5	1.5	

11.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	_	9.1	16.6	ns
(CK-Q)					50	_	11.9	19.6	
				$\textbf{3.3}\pm\textbf{0.3}$	15	_	6.7	13.2	
					50	_	8.9	16.7	
				5.0 ± 0.5	15	_	5.0	8.6	
					50	—	6.7	10.6	
3-state output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	$\textbf{2.5}\pm\textbf{0.2}$	15	—	7.6	16.1	ns
					50	—	10.7	19.0	
				$\textbf{3.3}\pm\textbf{0.3}$	15	_	5.7	12.8	
					50	_	8.1	16.3	
				5.0 ± 0.5	15	_	4.2	9.0	
					50	_	6.1	11.0	
3-state output disable time	t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	_	13.6	17.5	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	_	10.5	15.0	
				5.0 ± 0.5	50	_	8.2	10.1	
Maximum clock frequency	f _{MAX}		_	2.5 ± 0.2	15	60	95	_	MHz
					50	50	75	_	
				$\textbf{3.3}\pm\textbf{0.3}$	15	80	135	_	
					50	55	100	_	
				5.0 ± 0.5	15	130	180	_	
					50	85	135	_	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	2.5 ± 0.2	50	_		2.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50			1.5	
				5.0 ± 0.5	50	_	_	1.0	ns
Input capacitance	C _{IN}		_			_	4	10	pF
Output capacitance	C _{OUT}		—			_	6	_	pF
Power dissipation capacitance	C _{PD}	(Note 2)	_			_	26	—	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per latch)

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation.

 C_{PD} (total) = 14 + 12 × n

11.8. AC Characteristics (Upless otherwise specified $T_{r} = -40$ to 8

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	1.0	20.0	ns
(CK-Q)					50	1.0	23.0	
				$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	15.5	
					50	1.0	19.0	
				5.0 ± 0.5	15	1.0	10.0	
					50	1.0	12.0	
3-state output enable time	t _{PZL} ,t _{PZH}		R _L = 1 kΩ	$\textbf{2.5}\pm\textbf{0.2}$	15	1.0	19.0	ns
					50	1.0	22.0	
				3.3 ± 0.3	15	1.0	15.0	
					50	1.0	18.5	
				5.0 ± 0.5	15	1.0	10.5	
					50	1.0	12.5	
3-state output disable time	t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	$\textbf{2.5}\pm\textbf{0.2}$	50	1.0	20.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	1.0	17.0	
				5.0 ± 0.5	50	1.0	11.5	
Maximum clock frequency	f _{MAX}		—	2.5 ± 0.2	15	50	—	MHz
					50	40	—	
				$\textbf{3.3}\pm\textbf{0.3}$	15	65	—	
					50	45	—	
				5.0 ± 0.5	15	110	—	
					50	75	_	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)		2.5 ± 0.2	50	_	2.0	ns
				3.3 ± 0.3	50	_	1.5	
				5.0 ± 0.5	50	_	1.0	ns
Input capacitance	C _{IN}					_	10	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

11.9. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	$C_L (pF)$	Min	Max	Unit
Propagation delay time (CK-Q)	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	1.0	22.5	ns
					50	1.0	25.5	
				$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	17.5	
					50	1.0	21.0	
				5.0 ± 0.5	15	1.0	11.5	
					50	1.0	13.5	
3-state output enable time	t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	1.0	21.0	ns
					50	1.0	24.0	
				3.3 ± 0.3	15	1.0	17.0	
					50	1.0	20.5	
				5.0 ± 0.5	15	1.0	12.0	
					50	1.0	14.0	
3-state output disable time	t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	1.0	22.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	1.0	19.0	
				5.0 ± 0.5	50	1.0	13.0	
Maximum clock frequency	f _{MAX}		—	2.5 ± 0.2	15	40	—	MHz
					50	30	—	
				$\textbf{3.3}\pm\textbf{0.3}$	15	60	—	
					50	40	—	
				5.0 ± 0.5	15	100	—	
					50	65	—	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	2.0	ns
				$\textbf{3.3}\pm\textbf{0.3}$	50	_	1.5	
				5.0 ± 0.5	50	_	1.0	
Input capacitance	C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

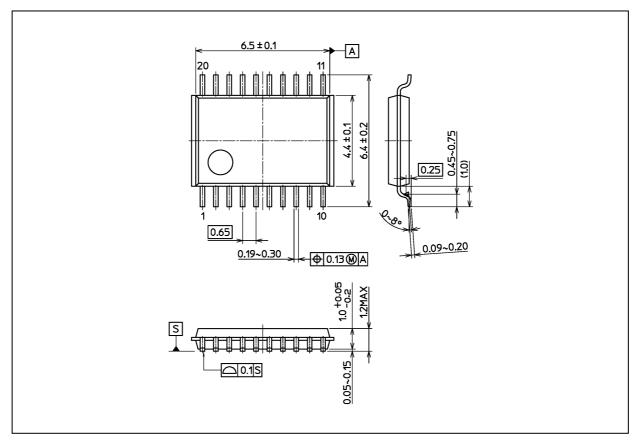
11.10. Noise Characteristics (Unless otherwise specified, $T_a = 25^{\circ}$ C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Max	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	C _L = 50 pF	3.3	0.4	_	V
			5.0	0.8	_	
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	3.3	-0.1		V
			5.0	-0.4	_	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low-level dynamic input voltage		C _L = 50 pF	5.0	_	1.5	V



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)	
Nickname: TSSOP20B		

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